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Diodes Incorporated DMN26D0UFB4-7

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>







DMN26D0UFB4

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	Ι _D T _A = +25°C
20V	$3.0\Omega @ V_{GS} = 4.5V$	240mA
200	6.0Ω @ V _{GS} = 1.8V	170mA

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions

Features and Benefits

- N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.05V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package, 0.4mm Maximum Package Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

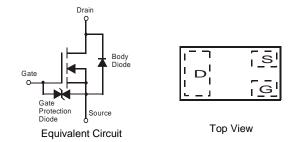
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)





X2-DFN1006-3

Bottom View



Ordering Information (Note 4)

Notes:

Part Number	Case	Packaging
DMN26D0UFB4-7	X2-DFN1006-3	3,000/Tape & Reel
DMN26D0UFB4-7B	X2-DFN1006-3	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

Alalogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
<1000ppm antimony compounds.

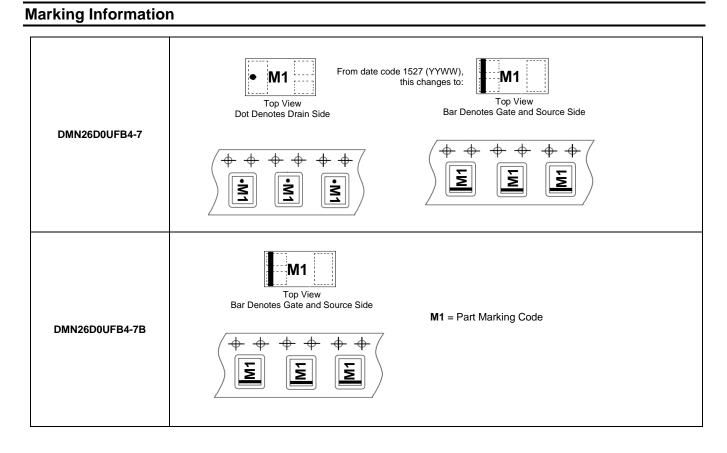
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

and Lead-free.





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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±10	V
Continuous Drain Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	240 190	mA
Continuous Drain Current (Note 5) V_{GS} = 1.8V	Steady State	T _A = +25°C T _A = +70°C	I _D	180 140	mA
Pulsed Drain Current - $T_P = 10 \mu s$			I _{DM}	805	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Total Power Dissipation (Note 5) @T _A = +25°C	PD	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	357	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.



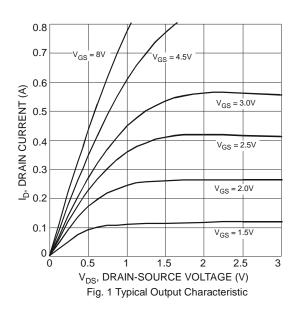


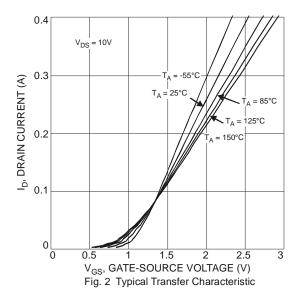
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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

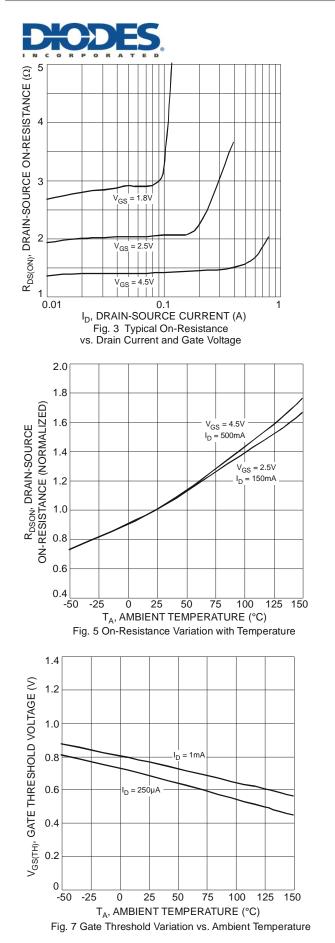
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 100 \mu A$	
Zero Gate Voltage Drain Current @ T_{C} = +25°C	I _{DSS}	_	_	500	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}	_	_	±1 ±100	μA nA	$V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(th)}	0.45	_	1.05	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS (ON)}		1.8 2.5 3.4 4.7	3.0 4.0 6.0 10.0	Ω	$\label{eq:VGS} \begin{array}{l} V_{GS} = 4.5 \text{V}, \ I_D = 100 \text{mA} \\ V_{GS} = 2.5 \text{V}, \ I_D = 50 \text{mA} \\ V_{GS} = 1.8 \text{V}, \ I_D = 20 \text{mA} \\ V_{GS} = 1.5 \text{V}, \ I_D = 10 \text{mA} \end{array}$	
Forward Transconductance	Y _{fs}	180	242	_	mS	V _{DS} = 10V, I _D = 0.1A	
Source-Drain Diode Forward Voltage	V _{SD}	0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C _{iss}	_	14.1	28.2	pF	V _{DS} = 15V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss		2.9	5.8	pF		
Reverse Transfer Capacitance	Crss	_	1.6	3.2	pF		
SWITCHING CHARACTERISTICS (Note 7)							
Turn-On Delay Time	t _{d(on)}	_	3.8	_			
Rise Time	tr	_	7.9	_		$V_{GS} = 4.5V, V_{DD} = 10V$ $I_D = 200mA, R_G = 2.0\Omega$	
Turn-Off Delay Time	t _{d(off)}	_	13.4		ns		
Fall Time	t _f	_	15.2	_			

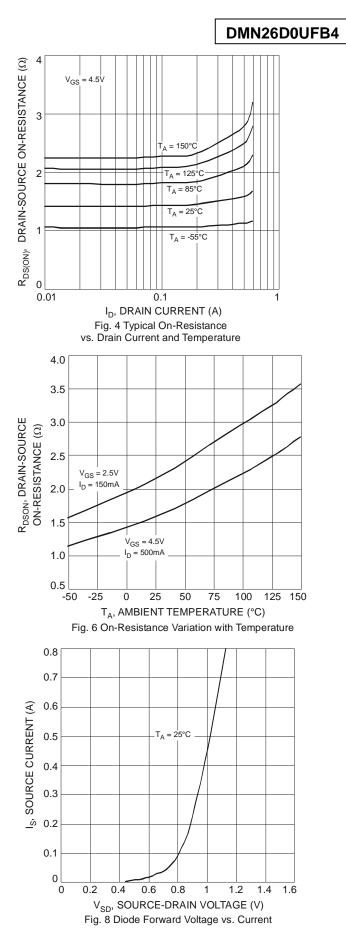
7. Guaranteed by design. Not subject to product testing.



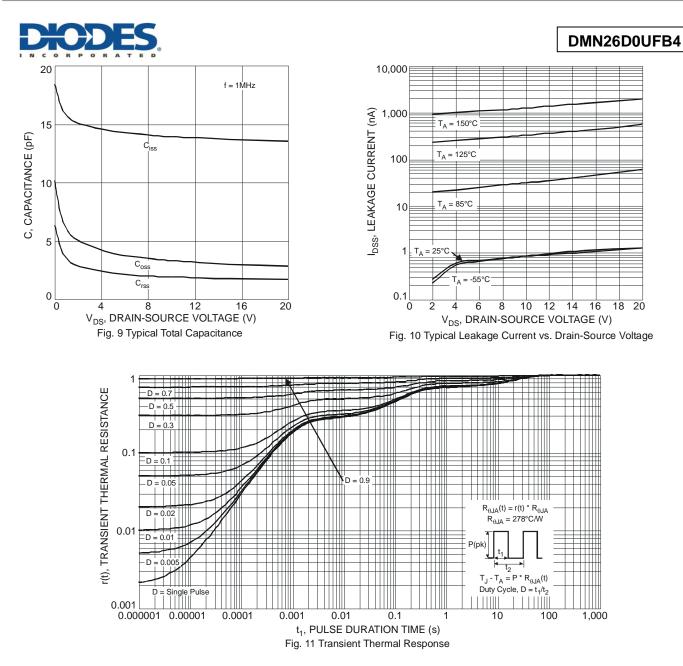












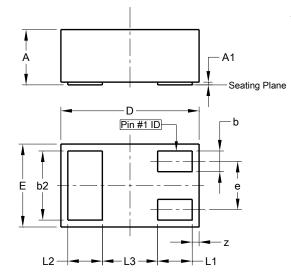




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Package Outline Dimensions

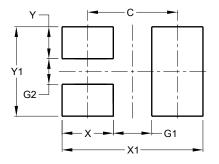
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN1006-3					
Dim	Min	Max	Тур		
Α		0.40			
A1	0.00	0.05	0.03		
b	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
Е	0.55	0.65	0.60		
е	1	1	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
L3	-	-	0.40		
Z	0.02	0.08	0.05		
All D	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70





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